

# Linear Materials

## Macroscopic Maxwell Equations

$$\vec{\nabla} \cdot \vec{B} = 0 \quad \vec{\nabla} \times \vec{E} + \frac{1}{c} \frac{\partial \vec{B}}{\partial t} = 0$$

$$\vec{\nabla} \cdot \vec{D} = 4\pi \rho \quad \vec{\nabla} \times \vec{H} = \frac{4\pi}{c} \vec{j} + \frac{1}{c} \frac{\partial \vec{D}}{\partial t}$$

where  $\rho$  and  $\vec{j}$  are macroscopic charge & current densities and

$$\vec{D} = \vec{E} + 4\pi \vec{P}$$

$\vec{P}$  is polarization density

$$\vec{H} = \vec{B} - 4\pi \vec{M}$$

$\vec{M}$  is magnetization density

To close these equations, we will in general need to know how  $\vec{P}$  and  $\vec{M}$  are related to the  $\vec{E}$  and  $\vec{B}$  in the material.

In some materials, there can be a finite  $\vec{P}$  or  $\vec{M}$  even if  $\vec{E}$  and  $\vec{B}$  are zero:

Ferromagnet:  $\vec{M}$  can be non zero even if  $\vec{B} = 0$

Ferroelectric:  $\vec{P}$  can be non zero even if  $\vec{E} = 0$

But more common are linear materials in which, for small  $\vec{E}$  and  $\vec{B}$ , one has  $\vec{P} \propto \vec{E}$  and  $\vec{M} \propto \vec{B}$ .

### linear dielectric

$$\vec{P} = \chi_e \vec{E}$$

$\chi_e$  is "electric susceptibility"  
 $\chi_e > 0$  for statics

$$\vec{D} = \vec{E} + 4\pi \vec{P} = (1 + 4\pi \chi_e) \vec{E}$$

$$\vec{D} = \epsilon \vec{E} \quad \text{with} \quad \epsilon = 1 + 4\pi \chi_e$$

$\epsilon$  is the dielectric constant

### linear magnetic materials

$$\vec{M} = \chi_m \vec{H}$$

$\chi_m$  is "magnetic susceptibility"

$\chi_m > 0 \Rightarrow$  paramagnetic

$\chi_m < 0 \Rightarrow$  diamagnetic

$$\vec{H} = \vec{B} - 4\pi \vec{M} = \vec{B} - 4\pi \chi_m \vec{H}$$

$$\vec{B} = (1 + 4\pi \chi_m) \vec{H}$$

$$\vec{B} = \mu \vec{H} \quad \text{with} \quad \mu = 1 + 4\pi \chi_m$$

$\mu$  is magnetic permeability

For statics,  $\chi_e > 0$  and  $\chi_m$  (or alternatively  $\epsilon$  and  $\mu$ ) are constants depending on the material.

When we consider dynamics we will see that  $\epsilon$  becomes a function of frequency.

## Clausius - Mossotti equation

### Electric susceptibility + atomic polarizability

If a field  $\vec{E}_{loc}$  is applied to an atom, it gets polarized

$$\vec{p} = \alpha \vec{E}_{loc}$$

↑                    ↑                    ↑  
atomic dipole moment    atomic polarizability    "local field" - field the atom sees

$\alpha$  is what one calculates from a microscopic theory

If  $\vec{E}_{loc} = \vec{E}$  the average field in the material then electric susceptibility given by

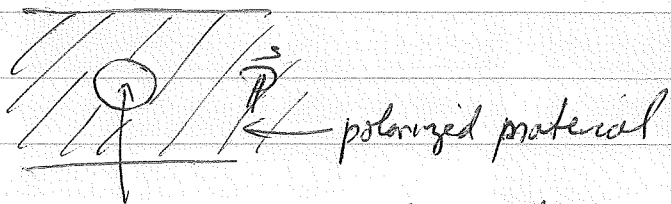
$$\vec{P} = n \vec{p} = n \alpha \vec{E}_{loc} = n \alpha \vec{E} = \chi_e \vec{E}$$

$\Rightarrow \chi_e = n \alpha$       where  $n =$  density of atoms

But a more careful consideration shows  $\vec{E}_{loc} \neq \vec{E}$   
The average field  $\vec{E}$  includes the electric field created by the polarized atom itself.  $\vec{E}_{loc}$ , the local field the atom sees, should exclude its own self field.

$$\vec{E} = \vec{E}_{loc} + \vec{E}_{atom}$$

↑                    ↑                    ↑  
average field    average field excluding atom    average field of the atom



cut out sphere whose volume is  $V_m$   
the volume per atom

$\vec{E}_{loc}$  is field excluding the field of the polarized sphere of volume  $V_m$ .

$\vec{E}_{atom}$  is field of the polarized sphere

$$\vec{E}_{atom} = -\frac{4\pi\vec{P}}{3} = -\frac{4\pi}{3}m\vec{p}$$

$$\vec{E}_{loc} = \vec{E} - \vec{E}_{atom} = \vec{E} + \frac{4\pi\vec{P}}{3} = \vec{E} + \frac{4\pi}{3}m\vec{p}$$

$$\vec{p} = \alpha \vec{E}_{loc} = \alpha \left( \vec{E} + \frac{4\pi}{3}m\vec{p} \right) = \alpha \vec{E} + \frac{4\pi m \alpha}{3} \vec{p}$$

$$\vec{p} = \frac{\alpha}{1 - \frac{4\pi m \alpha}{3}} \vec{E}$$

$$\vec{P} = m\vec{p} = \frac{\alpha m}{1 - \frac{4\pi m \alpha}{3}} \vec{E} = \chi_e \vec{E}$$

$$\chi_e = \frac{m \alpha}{1 - \frac{4\pi}{3} m \alpha}$$

or solve for  $\alpha$  in terms of  $\epsilon$

$$\chi_e = \frac{n\alpha}{1 - \frac{4\pi}{3}n\alpha} \Rightarrow \chi_e - \frac{4\pi}{3}n\alpha\chi_e = n\alpha$$

$$\Rightarrow \alpha = \frac{\chi_e}{n(1 + \frac{4\pi}{3}\chi_e)}$$

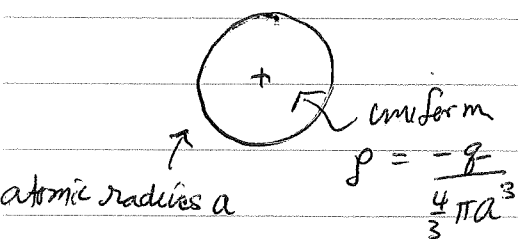
$$\epsilon = 1 + 4\pi\chi_e \Rightarrow \alpha = \frac{\epsilon - 1}{4\pi n} \frac{1}{(1 + \frac{\epsilon - 1}{3})}$$

relates atomic polarizability to measured dielectric constant

$$\alpha = \frac{3}{4\pi n} \left( \frac{\epsilon - 1}{\epsilon + 2} \right)$$

↑  
Clausius Mossotti  
or Lorentz-Lorenz equation

single model for  $\alpha$



field inside is  $E(r) = \frac{4\pi\rho}{3} r \hat{r}$

In external field  $E_0$ , electron cloud will be displaced from core by distance  $d$ . We can determine  $d$  by making a balance of forces:  $\Rightarrow qE_0 = q \frac{4\pi\rho d}{3}$

$$\chi_e = \frac{na^3}{1 - \frac{4\pi}{3}na^3}$$

$$\rho = qd = \frac{3}{4\pi q} qE_0 = \frac{3(\frac{4}{3}\pi a^3)}{4\pi q} qE_0 = a^3 E_0 \Rightarrow \alpha = a^3$$

if  $f = n \frac{4}{3}\pi a^3$  fraction of vol that is occupied by atoms

$$\chi_e = \frac{1}{4\pi} \frac{3f}{1-f}$$

## Linear dielectrics

bound charge is proportional to free charge

$$\rho_b = -\vec{\nabla} \cdot \vec{P} = -\vec{\nabla} \cdot (\chi_e \vec{E}) = -\vec{\nabla} \cdot \left( \frac{\chi_e}{\epsilon} \vec{D} \right)$$

if  $\chi_e$  (and hence  $\epsilon$ ) is spatially constant, then

$$\rho_b = -\frac{\chi_e}{\epsilon} \vec{\nabla} \cdot \vec{D} = -\frac{\chi_e}{\epsilon} 4\pi \rho$$

$$\boxed{\rho_b = -\frac{4\pi\chi_e}{1+4\pi\chi_e} \rho}$$

when free charge  $\rho = 0$ ,  
then  $\rho_b = 0$

$$\rho_{\text{total}} = \rho + \rho_b = \rho \left[ 1 - \frac{4\pi\chi_e}{1+4\pi\chi_e} \right] = \frac{\rho}{1+4\pi\chi_e} = \boxed{\frac{\rho}{\epsilon} = \rho_{\text{total}}}$$

bound charge "screens" the free charge so the total charge is reduced compared to the free charge.

## For linear dielectrics

### Statics

$$\vec{\nabla} \cdot \vec{D} = 4\pi\rho$$

$$\vec{\nabla} \times \vec{E} = 0$$

$$\vec{D} = \epsilon \vec{E} \Rightarrow \vec{\nabla} \cdot (\epsilon \vec{E}) = 4\pi\rho$$

if  $\epsilon$  is constant in space then  $\epsilon \vec{\nabla} \cdot \vec{E} = 4\pi\rho$

$$\left. \begin{aligned} \vec{\nabla} \cdot \vec{E} &= 4\pi\rho/\epsilon = 4\pi\rho_{\text{tot}} \\ \vec{\nabla} \times \vec{E} &= 0 \end{aligned} \right\} \begin{array}{l} \text{look just like ordinary} \\ \text{electrostatics but} \\ \text{with } \rho \rightarrow \rho/\epsilon \end{array}$$

Alternatively, could write  $\vec{E} = \vec{D}/\epsilon$

$$\Rightarrow \vec{\nabla} \times (\vec{D}/\epsilon) = 0$$

$$\Rightarrow \vec{\nabla} \times \vec{D} = 0 \quad \text{when } \epsilon \text{ constant in space}$$

$$\left. \begin{aligned} \vec{\nabla} \cdot \vec{D} &= 4\pi\rho \\ \vec{\nabla} \times \vec{D} &= 0 \end{aligned} \right\} \begin{array}{l} \text{looks just like ordinary} \\ \text{electrostatics, but with } \vec{E} \rightarrow \vec{D} \end{array}$$

Complication arises at interface between dielectrics (or between dielectric and vacuum). At interface,  $\epsilon$  is not constant  $\Rightarrow \vec{\nabla} \times \vec{D} \neq 0$ .

What we can do is to solve for  $\vec{E}$  or  $\vec{D}$  inside each dielectric separately, and then use the boundary conditions

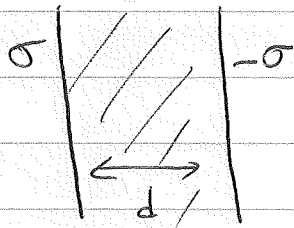
$$\hat{n} \cdot (\vec{D}^{\text{above}} - \vec{D}^{\text{below}}) = 4\pi\sigma$$

$$\hat{t} \cdot (\vec{E}^{\text{above}} - \vec{E}^{\text{below}}) = 0$$

to match solutions across the interfaces.

A similar story holds for linear magnetic materials

Single example: parallel plate capacitor filled with a dielectric



$\sigma$  free charge

What is  $E$  between plates?

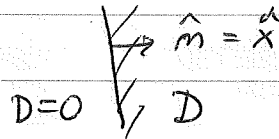
We know  $\vec{E} = \vec{D} = 0$  outside plates

Between plates  $\vec{\nabla} \cdot \vec{D} = 0$  as  $\rho = 0$

$$\vec{D} = D(x) \hat{x} \Rightarrow \frac{\partial D}{\partial x} = 0 \Rightarrow D \text{ is constant}$$

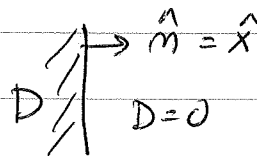
Boundary conditions:

left side plate



$$\hat{x} \cdot (\vec{D}^{\text{above}} - \vec{D}^{\text{below}}) = D = 4\pi\sigma$$

right side plate



$$\hat{x} \cdot (\vec{D}^{\text{above}} - \vec{D}^{\text{below}}) = -D = 4\pi(-\sigma)$$

$D = 4\pi\sigma$  as before

$$\Rightarrow \vec{D} = 4\pi\sigma \hat{x}$$

$$\vec{E} = \frac{\vec{D}}{\epsilon} = \frac{4\pi\sigma}{\epsilon} \hat{x}$$

electric field reduced by factor  $1/\epsilon$  as compared to capacitor with vacuum between plates

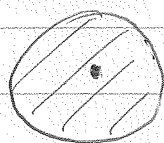
see Jackson section 4.4 for more interesting examples  
- dielectric sphere in uniform applied  $E$

see Jackson section (5.11) (5.12) for an interesting magnetic b.c. problem  
- spherical permeable shell in uniform applied  $B$

going sec 95



## point charge within a dielectric sphere



pt charge  $q$  at center of dielectric sphere of radius  $R$ , dielectric const  $\epsilon$

$$\vec{\nabla} \cdot \vec{D} = 4\pi q = \oint_S da \hat{n} \cdot \vec{D} = 4\pi q_{\text{enc}} \quad \text{all } r$$

From symmetry  $\vec{D}(r) = D(r) \hat{r}$

$$\oint da \hat{n} \cdot \vec{D} = 4\pi r^2 D(r) = 4\pi q$$

sphere of radius  $r$   $\rightarrow$

$$\vec{D} = \frac{q}{r^2} \hat{r} \quad \text{all } r$$

$$\Rightarrow \vec{E}(r) = \begin{cases} \frac{q}{\epsilon r^2} \hat{r} & r < R \\ \frac{q}{r^2} \hat{r} & r > R \end{cases}$$

can check that tangential component of  $\vec{E}$  is continuous and normal component of  $\vec{D}$  is continuous as there is no free  $\sigma$  at surface of dielectric.

normal component of  $\vec{E}$  jumps by

$$\hat{n} \cdot (\vec{E}^{\text{above}} - \vec{E}^{\text{below}}) = \frac{q}{R^2} - \frac{q}{\epsilon R^2} = \frac{q}{R^2} \left(1 - \frac{1}{\epsilon}\right) = \frac{q}{R^2} \left(\frac{\epsilon-1}{\epsilon}\right)$$

$$= \frac{q}{R^2} \left( \frac{4\pi \kappa \epsilon}{1 + 4\pi \kappa \epsilon} \right) = 4\pi \sigma_{\text{total}} = 4\pi \sigma_b$$

$$\Rightarrow \sigma_b = \frac{q}{4\pi R^2} \left( \frac{4\pi \kappa \epsilon}{1 + 4\pi \kappa \epsilon} \right) = \frac{q \kappa \epsilon}{R^2 \epsilon}$$

We can check this directly

$$\vec{P} = \chi_e \vec{E} = \frac{\chi_e q}{\epsilon} \frac{\hat{r}}{r^2}$$

$$\rho_b = -\vec{\nabla} \cdot \vec{P} = -\frac{\chi_e q}{\epsilon} 4\pi \delta(r)$$

↑  
bound charge at origin  $q_b = -\frac{\chi_e q}{\epsilon}$

total charge at origin is  $q + q_b = q \left(1 - \frac{4\pi\chi_e}{\epsilon}\right)$

$$\epsilon = 1 + 4\pi\chi_e \quad = q \left(\frac{\epsilon - 4\pi\chi_e}{\epsilon}\right) = \frac{q}{\epsilon} \text{ screened charge}$$

at surface,

$$\sigma_b = \hat{n} \cdot \vec{P} = \frac{\chi_e q}{\epsilon R^2}$$

agrees with what we get from jump in  $\hat{n} \cdot \vec{E}$ .

Note: inside the dielectric the  $\vec{E}$  field is that of the screened point charge  $\frac{q}{\epsilon}$ .  
outside the dielectric  $\vec{E}$  is just that of the free charge  $q$ . There is no evidence in  $\vec{E}_{out}$  that the dielectric even exists!